## NSN 5961-00-093-3502

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View Online at https://aerobasegroup.com/nsn/5961-00-093-3502 **Inclosure Material:** Plastic **Overall Length:** 0.765 inches **Overall Diameter:** 0.380 inches **End Application:** Instrument landing system (mark1c) **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 2.50 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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